## NSN 5961-01-107-2016



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-107-2016 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 80131-release5996 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig:

A110a0